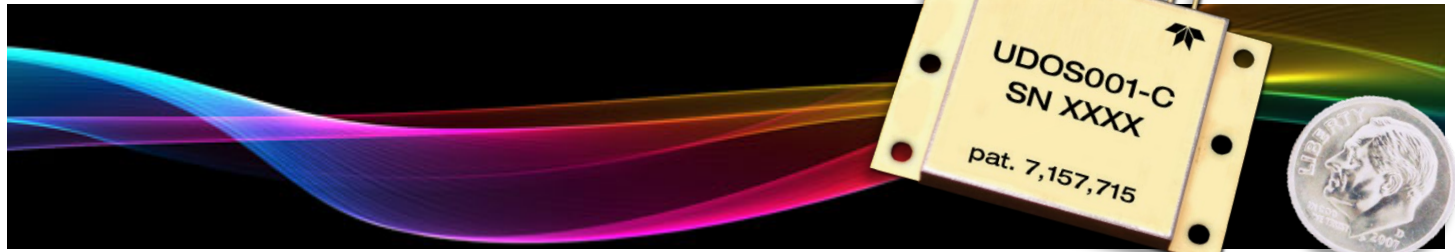


# μDOS001/007 Micro Dosimeters

## Product Specifications



### Description

The Micro Dosimeters (P/N UDOS001, and High LET extended temperature range version UDOS007) are compact hybrid microcircuits which directly measure total ionizing dose (TID) absorbed by an internal silicon test mass. The test mass simulates silicon die of integrated circuits on-board a host spacecraft in critical mission payloads and subsystems. By accurately measuring the energy absorbed from electrons, protons, and gamma rays, an estimate of the dose absorbed by other electronic devices on the same vehicle can be made. Each Micro Dosimeter can operate from a wide range of power supply voltages. The accumulated dose is presented to three cascaded dc linear outputs and one pseudo-logarithmic output giving a dose resolution of 15  $\mu$ rad(Si) and a measurement range up to 40 krad(Si). These outputs are intended to be directly connected to most analog-to-digital converters (ADCs) or spacecraft housekeeping analog inputs (0 - 5 V range), which makes minimal demands on the host vehicle.

### Features/Benefits

- Enables routine monitoring of spacecraft radiation environment
- Custom microchip in a small footprint package which results in significantly lower weight and power than alternative devices
- Can be mounted in multiple locations on spacecraft
- Correlates environmental models and ray-tracing analyses with real in-flight measurements
- Provides total mission dose to aid in diagnosis of spacecraft anomalies that result from changes in environmental fluxes
- Dosimeters can be integrated to standard spacecraft housekeeping systems
- Measures up to 40 krad(Si)
- Mechanical dimensions: 1.4" x 1.0" x 0.2"
- 20 grams in weight
- 10 mA from 13 Vdc to 40 Vdc input
- Simple linear analog output
- Class H-equivalent screening available

### Part Number Description

Part Number	Description
UDOS001-C	Micro Dosimeter – Commercial
UDOS001-H	Micro Dosimeter – Class H Equivalent Screening
UDOS007-C	Micro Dosimeter – Commercial
UDOS007-H	Micro Dosimeter – Class H Equivalent Screening

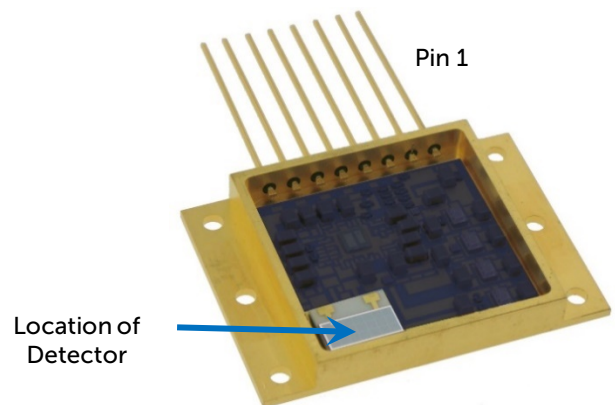
### Better than Industry Standards

- First compact microcircuit that provides a repeatable measurement of radiation dose over a wide range of energies
- Uses a patented integrator architecture to produce a flat energy response
- High reliability hermetic packaging

### Classification Description

- Commercial - Electrical Test Only
- Class H - MIL-PRF 38534 Equivalent Screening

### Location of Detector



## Principle of Operation

Each model incorporates a silicon detector (3 mm x 7 mm x 250  $\mu\text{m}$ ) and a pulse-processing architecture that creates a shaped pulse in response to ionizing radiation. This pulse is integrated into an accumulator circuit. The integration continues for each event until a preset limit is reached. When this happens, a Quanta of charge is removed from the integrator equal to a value of 15  $\mu\text{rads}$ , and a counter value is incremented. This counter is divided into sub-groups of 8 bits which are each presented to a D/A converter. The DAC Low range gives dose as 15  $\mu\text{rads}$  per 19.5 mV step, the DAC Medium range is 256 times the Low range, and the High is 256 times the Medium range. The dosimeter will retain the value of the dose for as long as it is powered. A Pseudo-Log output can be sampled at a very low rate to monitor the total dose over extended periods of time. The other DAC ranges can be sampled at higher rates to obtain useful dose rate measurements. The High LET UDOS007 Dosimeter incorporates a raised energy level input threshold. The increased minimum energy level allows for accumulating and counting higher levels of detected ionizing radiation.

Note: The dosimeter does not measure incident energy directly. The dosimeter measures the amount of energy absorbed in the silicon detector due to the energy loss of the particle as it passes through the detector volume.

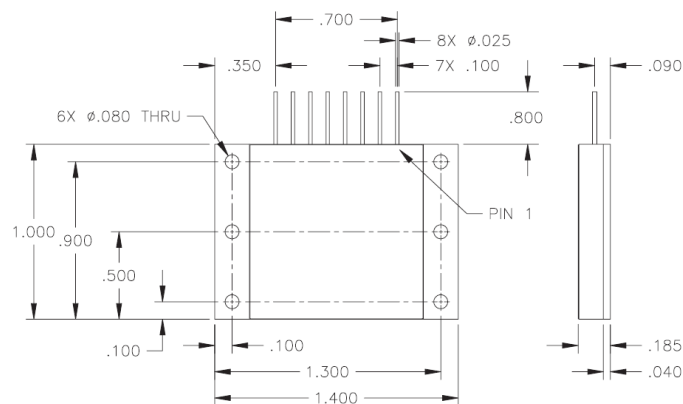
## Ratings

Parameters		Symbol	Min	Max	Units
Supply Voltage		$V_{CC}$	13	40	Vdc
Supply Current		$I_{CC}$	8	12	mA
Dose Rate			1	10,000	$\mu\text{rad}(\text{Si})/\text{sec}$
Integrated Error			-20	+20	%
Low Energy Threshold	UDOS001	$E_t$	60	120	keV
	UDOS007	$E_t$	800	1200	keV
Energy Range		$E_r$	$E_t$	15	MeV
Dose Sensitivity	UDOS001	S	14	16	$\mu\text{rad}(\text{Si})/\text{step}$
	UDOS007	S	19	21	$\mu\text{rad}(\text{Si})/\text{step}$
DAC Voltage Step			15	25	mV
DAC Output Voltage Swing			0	5	V
DAC Output Impedance			8	12	$k\Omega$
Relative Humidity		RH	0	90	%
Operating Temperature	UDOS001	$T_O$	-30	+40	$^{\circ}\text{C}$
	UDOS007	$T_O$	-30	+70	$^{\circ}\text{C}$
Storage Temperature		$T_S$	-40	+110	$^{\circ}\text{C}$

## Pin Specifications

Pin	Description	Notes
1	Power	
2	Ground	
3	Reserved – connect to ground during normal operation	
4	N/C – should be formed and mounted	
5	DAC Output – Low Range	Low
6	DAC Output – Medium Range	Medium
7	DAC Output – High Range	High
8	DAC Output – Pseudo-Log	Log

## Mechanical Configuration



Drawing shows the hermetic package, mounting flange and 8 external connections. All dimensions given are inches, tolerances  $\pm 0.005$ . The package walls are 0.040 inch thick, cover is 0.010 inch thick. Pin 1 is top-right in the diagram.

## Radiation Survivability

Xe-beam testing done at Lawrence Berkeley Labs demonstrated latch-up immunity up to 67.8 LET (MeV-cm<sup>2</sup>/mg). Harsh proton susceptibility testing was performed using a high energy beam and UDOS001 showed no degradation up to 40 krad(Si).

## DAC Output Conversions

DACx	Dose Conversion	Range
Low (Pin 5)	15 μrad(Si)/19.5 mV	0 – 3.8 mrad(Si)
Medium (Pin 6)	3.8 mrad (Si)/19.5 mV	0 – 0.98 rad(Si)
High (Pin 7)	0.98 rad(Si)/19.5 mV	0 – 252 rad (Si)
Log (Pin 8)	Detailed table will be provided upon request	0 – 40 krad(Si)

## Application Notes

### Grounding

The dosimeter case is electrically connected to pin 2 inside the hybrid in order to minimize electromagnetic interference on the sensitive detector electronics. Isolate the dosimeter case from structural chassis to avoid ground loops.

### Supply Voltage

Ensure voltage input is stable and maintains the required voltage level. No ripple from dc converters, on board voltage supply should be clean.

### Energy Threshold

The dosimeter typically will integrate the dose absorbed by the silicon detector for energy deposits in the nominal range of 100 keV to 15 MeV.

### Calibration

Each dosimeter can be exposed to a known “fixed” source level of ionizing dose by the end user to calibrate the dosage input to DAC output. Positioning of the dosimeter and area shielding can be used for directional mapping of radiation events.

### DAC/Log Output Resets

When any of the DAC or Log outputs reaches its maximum value of 5-volts, the output is reset to 0-volts and the next higher DAC is incremented by 1 step. If the device reaches its maximum dose (i.e., the internal dose counter reaches its maximum), the Micro Dosimeter will reset all outputs and continue stepping in response to radiation. The outputs should be buffered or connected to a high impedance ADC. During operation, the outputs should be sampled at the same time to avoid TID ambiguity.

## Export Classification

The dosimeters are classified 1A999.a for export purposes.

## Quality Flow

The Micro Dosimeter hybrids are built using commercial grade and military grade components. All assembled hybrids receive full electrical testing at HIGH, LOW, and ROOM operating temperature ranges.

Class H-equivalent screening options are available as per the screening table below:

Class H Screening	
<b>Hybrid Microcircuit 100% Testing</b>	
✓	Internal visual inspection
✓	Temperature cycling 10 times from -65°C to +150°C
✓	Constant acceleration 3,000 G
✓	Burn-in 160 hours at 125°C, PDA 10%
✓	Seal (fine and gross)
✓	Electrical test at min, max and room temp
✓	External Visual

**Class H Screening Table**

## Notes

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### Product Specification

The data sheet contains final data. In the event Teledyne e2v HiRel Electronics decides to change the specifications, Teledyne e2v HiRel will notify customers of the intended changes by issuing a CNF (Customer Notification Form). The information in this data sheet is believed to be reliable. However, Teledyne e2v HiRel assumes no liability for the use of this information. Use shall be entirely at the user's own risk. No patent rights or licenses to any circuits described in this data sheet are implied or granted to any third party. Teledyne e2v HiRel's products are not designed or intended for use in devices or systems intended for surgical implant, or in other applications intended to support or sustain life, or in any application in which the failure of the Teledyne e2v HiRel product could create a situation in which personal injury or death might occur. Teledyne e2v HiRel assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

### Data

Teledyne e2v HiRel requests that the Micro Dosimeter data be made available to The Aerospace Corporation for the purpose of improving space environment models used to predict radiation dose with the multitude of Micro Dosimeter data obtained from orbits.

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